

# . reescale Semiconductor Technical Data

Document Number: MHW8182CN

Rev. 3, 4/2006

**RoHS** 

# V ROIL

# **CATV Amplifier Module**

# **Features**

- Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

# **Applications**

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation

# **Description**

- 24 Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module
- Replaced MHW8182C. There are no form, fit or function changes with this
  part replacement.
- · RoHS Compliant

# MHW8182CN

860 MHz 19.1 dB GAIN 128-CHANNEL CATV AMPLIFIER MODULE

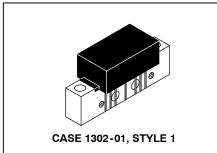


Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+70	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

Table 2. Electrical Characteristics ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	860	MHz
Power Gain	50 MHz 860 MHz	G <sub>p</sub>	18 18.2	18.5 19.1	19 20.5	dB
Slope	40 - 860 MHz	S	0	0.7	2.5	dB
Gain Flatness (40 - 860 MHz, Peak to Valley)		G <sub>F</sub>	_	0.3	0.6	dB
Return Loss — Input/Output (Z <sub>o</sub> = 75 Ohms) @ 40 MHz @ f > 40 MHz (Derate)		IRL/ORL	20 —	<u> </u>	 0.005	dB dB/MHz
Composite Second Order (V <sub>out</sub> = +38 dBmV/ch., Worst Case) (V <sub>out</sub> = +40 dBmV/ch., Worst Case) (V <sub>out</sub> = +44 dBmV/ch., Worst Case)	128-Channel FLAT 110-Channel FLAT 77-Channel FLAT	CSO <sub>128</sub> CSO <sub>110</sub> CSO <sub>77</sub>	_ _ _	-71 -70 -70	-64 -63 -64	dBc



**Table 2. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted) (continued)

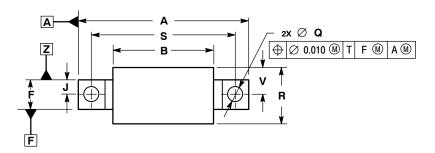
Characteristic		Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion @ Ch 2 ( $V_{out} = +38 \text{ dBmV/ch.}$ , FM = 55 MHz) ( $V_{out} = +40 \text{ dBmV/ch.}$ , FM = 55 MHz) ( $V_{out} = +44 \text{ dBmV/ch.}$ , FM = 55 MHz)	128-Channel FLAT 110-Channel FLAT 77-Channel FLAT	XMD <sub>128</sub> XMD <sub>110</sub> XMD <sub>77</sub>	_ _ _	-68 -66 -61	-65 -64 -59	dBc
Composite Triple Beat (V <sub>out</sub> = +38 dBmV/ch., Worst Case) (V <sub>out</sub> = +40 dBmV/ch., Worst Case) (V <sub>out</sub> = +44 dBmV/ch., Worst Case)	128-Channel FLAT 110-Channel FLAT 77-Channel FLAT	CTB <sub>128</sub> CTB <sub>110</sub> CTB <sub>77</sub>	_ _ _	-69 -68 -66	-66 -66 -64	dBc
Noise Figure	50 MHz 550 MHz 750 MHz 860 MHz	NF	_ _ _ _	4.0 4.5 5.0 5.5	5.0 — 6.5 7.5	dB
DC Current (V <sub>DC</sub> = 24 V, T <sub>C</sub> = 30°C)		I <sub>DC</sub>	180	220	240	mA

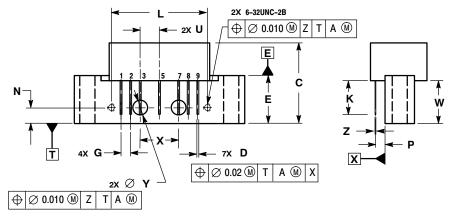
# ARCHIVE INFORMATION



**ARCHIVE INFORMATION** 

# **PACKAGE DIMENSIONS**





- CONTROLLING DIMENSION: INCH.
   INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Е	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.620	8.255	
G	0.100 BSC		2.540 BSC		
J	0.156	BSC	3.962	BSC	
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
P	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.240	
S	1.500 BSC		38.100 BSC		
U	0.200	BSC	5.080 BSC		
٧		0.250		6.350	
W	0.435		11.049		
Х	0.400 BSC		10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
  PIN 1. RF INPUT
  2. GROUND
  3. GROUND
  4. DELETED
  5. VDC
  6. DELETED
  7. GROUND
  8. GROUND
  9. RF OUTPUT

**CASE 1302-01 ISSUE E** 



# ARCHIVE INFORMATION

# How to Reach Us:

Home Page:

www.freescale.com

E-mail:

support@freescale.com

# **USA/Europe or Locations Not Listed:**

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

# Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

# Japan:

Freescale Semiconductor Japan Ltd. Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

# Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

## For Literature Requests Only:

Freescale Semiconductor Literature Distribution Center P.O. Box 5405 Denver, Colorado 80217 1-800-441-2447 or 303-675-2140 Fax: 303-675-2150 LDCForFreescaleSemiconductor@hibbertgroup.com Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or quarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale <sup>™</sup> and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners. © Freescale Semiconductor, Inc. 2006, 2008. All rights reserved.

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics of their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see http://www.freescale.com or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to http://www.freescale.com/epp.



Document Number: MHW8182CN

Rev. 3, 4/2006